NSN 5961-01-365-5032

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-365-5032 **Inclosure Material:** Metal **Overall Length:** 1.925 inches **Terminal Length:** 0.188 inches **Overall Height:** 0.270 inches **Overall Width:** 0.475 inches **Mounting Facility Quantity: Component Name And Quantity:** 4 transistor **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 500.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 4.50 amperes drain current all transistor **Power Rating Per Characteristic:** 50.0 watts total device dissipation all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 130.0 degrees celsius ambient air **Test Data Document:** 28527-3131517 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 12 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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